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TOSHIBA

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHC574F,TC74VHC574FW,TC74VHC574FT,TC74VHC574FK

Octal D-Type Flip Flop with 3-State Output

The TC74VHC574 is advanced high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type flip-flop is controlled by a clock input (CK) and a output enable input (\overline{OE}).

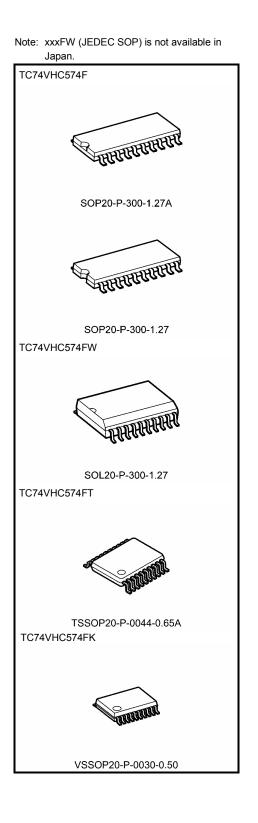
When the \overline{OE} input is high, the eight outputs are in a high impedance state.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

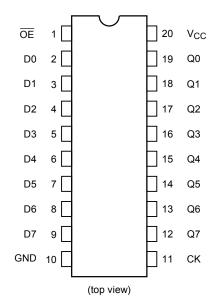
- High speed: $f_{max} = 180 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A (max)$ at $Ta = 25^{\circ}C$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: VCC (opr) = 2 to 5.5 V
- Low noise: VOLP = 1.2 V (max)
- Pin and function compatible with 74ALS574

Weight	
SOP20-P-300-1.27A	: 0.22 g (typ.)
SOP20-P-300-1.27	: 0.22 g (typ.)
SOL20-P-300-1.27	: 0.46 g (typ.)
TSSOP20-P-0044-0.65A	: 0.08 g (typ.)
VSSOP20-P-0030-0.50	: 0.03 g (typ.)



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Pin Assignment



IEC Logic Symbol

0E <u>(1)</u> CK <u>(11)</u>	EN > C1		
D0 (2) D1 (3) D2 (4) D3 (5) D4 (6) D5 (7) D6 (8) D7 (9)	1D		(19) Q0 (18) Q1 (17) Q2 (16) Q3 (15) Q4 (14) Q5 (13) Q6 (12) Q7

Truth Table

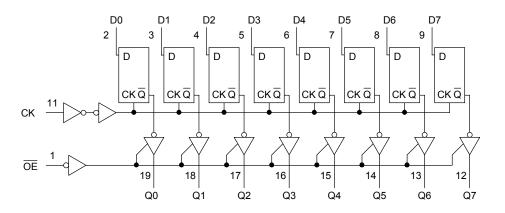
	Inputs	Output				
ŌE	СК	D	Output			
Н	Х	Х	Z			
L		Х	Qn			
L		L	L			
L		Н	Н			

X: Don't care

Z: High impedance

Qn: No change

System Diagram



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	IIK	-20	mA
Output diode current	I _{OK}	±20	mA
DC output current	IOUT	±25	mA
DC V _{CC} /ground current	ICC	±75	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0 to 5.5	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 (V _{CC} = 3.3 ± 0.3 V)	ns/V
	ui/uv	0 to 20 (V _{CC} = 5 \pm 0.5 V)	115/ V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol		Test Condition		٦	「a = 25°0	0		i = 0 85°C	Unit	
	-)			$V_{CC}(V)$	Min	Тур.	Max	Min	Max		
			2.0	1.50	-	_	1.50	_			
High-level input voltage	VIH		_	3.0 to 5.5	V _{CC} × 0.7	_	_	V _{CC} × 0.7	_	V	
Low-level input				2.0	_	_	0.50	_	0.50		
voltage	V _{IL}		_		_	_	V _{CC} × 0.3	_	V _{CC} × 0.3	V	
				2.0	1.9	2.0	_	1.9	_		
			I _{OH} = -50 μA	3.0	2.9	3.0	—	2.9	—		
High-level output voltage	V _{OH}	VIN = VIH or VIL		4.5	4.4	4.5	-	4.4	_	V	
, i i i i i i i i i i i i i i i i i i i			I _{OH} = −4 mA	3.0	2.58			2.48			
			I _{OH} = -8 mA	4.5	3.94		-	3.80	_		
		V _{IN} = V _{IH} or V _{IL}		2.0	-	0.0	0.1		0.1		
			I _{OL} = 50 μA	3.0	—	0.0	0.1	—	0.1		
Low-level output voltage	V _{OL}			4.5	-	0.0	0.1	-	0.1	V	
Ũ			I _{OL} = 4 mA	3.0	-	Ι	0.36		0.44		
			I _{OL} = 8 mA	4.5	-		0.36	-	0.44		
3-state output off-state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5	_	_	±0.25	_	±2.50	μA	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1		±1.0	μA	
Quiescent supply current	ICC	V _{IN} = V _{CC} o	r GND	5.5	_	_	4.0		40.0	μA	

Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol Test Condition			Ta = 25°C		Ta = -40 to 85°C	Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	t _{w (H)}		3.3 ± 0.3	_	5.0	5.0	ns
(CK)	t _{w (L)}	—	5.0 ± 0.5	—	5.0	5.0	115
Minimum set-up time	+	_	3.3 ± 0.3	—	3.5	3.5	20
Minimum set-up time	ts		5.0 ± 0.5	—	3.5	3.5	ns
Minimum hold times		3.3 ± 0.3	_	1.5	1.5	20	
Minimum hold time	t _h	—	5.0 ± 0.5	-	1.5	1.5	ns

AC Characteristics (input: t_r = t_f = 3 ns)

Characteristics	Symbol	Tes	st Condition		-	Ta = 25°0	0	Ta −40 to	Unit	
	-)		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
			3.3 ± 0.3	15	_	8.5	13.2	1.0	15.5	
Propagation delay time	t _{pLH}		5.5 ± 0.5	50	_	11.0	16.7	1.0	19.0	ns
(CK-Q)	t _{pHL}	_	5.0 ± 0.5	15	_	5.6	8.6	1.0	10.0	115
			5.0 ± 0.5	50		7.1	10.6	1.0	12.0	
			3.3 ± 0.3	15	١	8.2	12.8	1.0	15.0	
3-state output enable	t _{pZL}	R _I = 1 kΩ	5.5 ± 0.5	50	-	10.7	16.3	1.0	18.5	ns
time t _{pZH}	t _{pZH}	RL - 1 KQ	5.0 ± 0.5	15	١	5.9	9.0	1.0	10.5	- 115
			5.0 ± 0.5	50		7.4	11.0	1.0	12.5	
3-state output disable	t _{pLZ}	R _L = 1 kΩ	3.3 ± 0.3	50		11.0	15.0	1.0	17.0	ns
time	t _{pHZ}		5.0 ± 0.5	50	-	7.1	10.1	1.0	11.5	115
	£		3.3 ± 0.3	15	80	125	_	65	_	MHz
Maximum clock				50	50	75		45	_	
frequency	f _{max}		5.0 ± 0.5	15	130	180		110	-	
			5.0 ± 0.5	50	85	115	_	75	-	
Output to output skew	t _{osLH}	(Note 1)	3.3 ± 0.3	50			1.5	—	1.5	ns
	t _{osHL}	(NOLE T)	1) 5.0 ± 0.5	50	-	_	1.0	_	1.0	115
Input capacitance	C _{IN}		_		—	4	10	_	10	pF
Output capacitance	C _{OUT}		_		-	6	-	—	_	pF
Power dissipation capacitance	C _{PD}			(Note 2)	_	28	_	_	_	pF

Note 1: Parameter guaranteed by design.

 $t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 (per F/F)$

And the total C_{PD} when n pcs. of latch operate can be gained by the following equation:

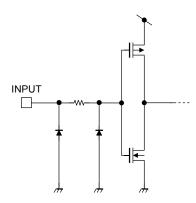
C_{PD} (total) = 20 + 8⋅n

Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$) (Note)

Characteristics	Symbol	Test Condition	_	Ta =	Unit	
Characteristics	Symbol		V _{CC} (V)	Тур.	Max	Onit
Quiet output maximum dynamic V _{OL}	Vala	C ₁ = 50 pF	5.0	0.8	1.0	V
	V _{OLP}	CL - 50 PF	5.0	(0.9)	(1.2)	
Quiet output minimum dynamia Var	V _{OLV}	C _L = 50 pF	5.0	-0.8	-1.0	V
Quiet output minimum dynamic V _{OL}			5.0	(-0.9)	(-1.2)	
Minimum high level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	_	1.5	V

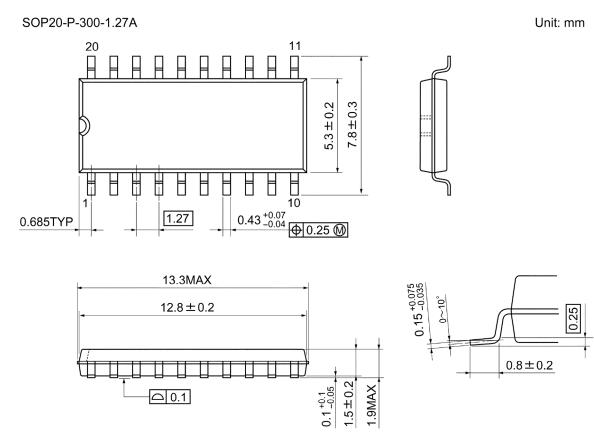
Note: The value in () only applies to JEDEC SOP (FW) devices.

Input Equivalent Circuit



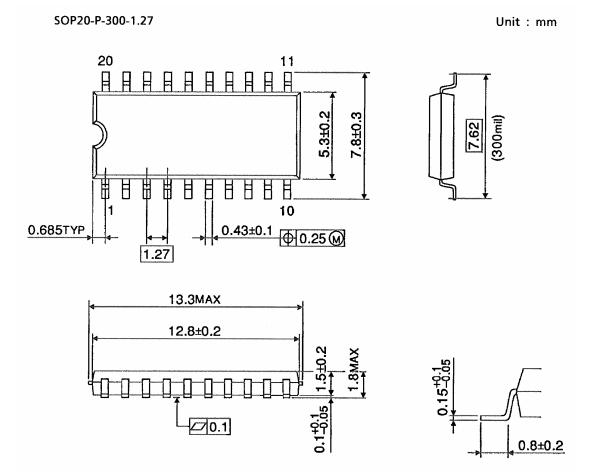
TOSHIBA

Package Dimensions



Weight: 0.22 g (typ.)

Package Dimensions

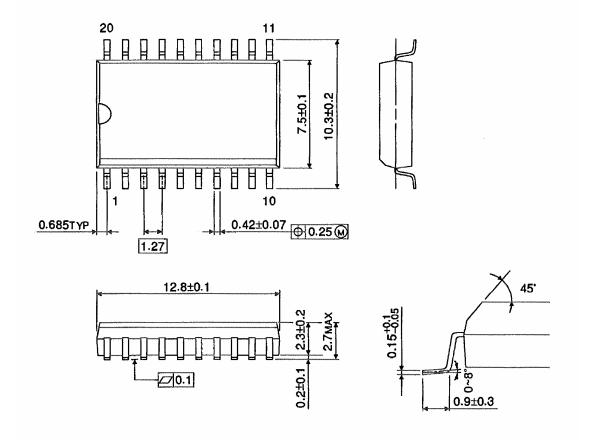


Weight: 0.22 g (typ.)

Package Dimensions (Note)

SOL20-P-300-1.27

Unit : mm



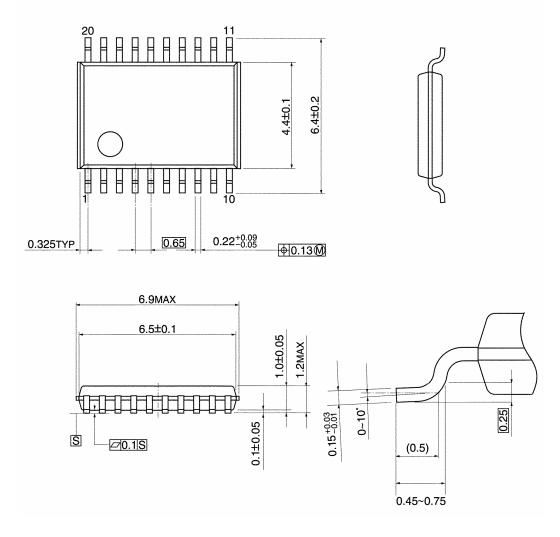
Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm

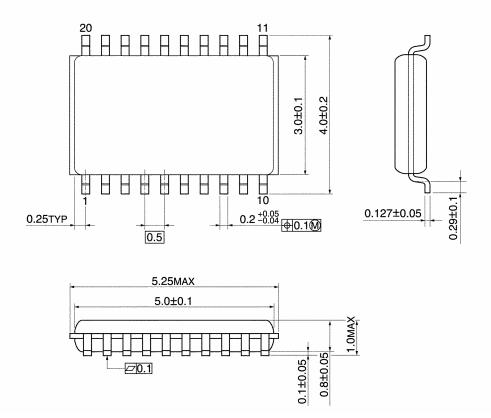


Weight: 0.08 g (typ.)

Package Dimensions

VSSOP20-P-0030-0.50

Unit: mm



Weight: 0.03 g (typ.)

Note: Lead (Pb)-Free Packages

SOP20-P-300-1.27A TSSOP20-P-0044-0.65A VSSOP20-P-0030-0.50

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